## NSN 5961-00-462-3613



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-462-3613 **Inclosure Material:** Metal **Overall Length:** Between 0.480 inches and 0.535 inches Overall Diameter: 0.775 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-63 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Mounting hardware and hermetically sealed case **Overall Width Across Flats:** Between 0.855 inches and 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 

N/a

3 tab, solder lug Shelf Life:

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A110a0